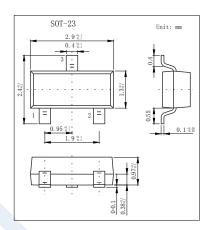
SMD Type Diodes

Switching Diodes 1SS181

Features

- Low forward voltage. :VF(3)=0.92V(Typ.)
- Fast reverse recovery time :trr=1.6ns(Typ.)
- Small total capacitance :CT=2.2pF(Typ.)





■ Absolute Maximum Ratings Ta = 25 °C

| Parameter | Symbol | Rating | Unit |
|-------------------------|--------|-------------|------------------------|
| Peak reverse voltage | Vrm | 85 | ٧ |
| Reverse voltage | VR | 80 | V |
| Average forward current | lo | 100 | mA |
| Peak forward current | IFМ | 300 | mA |
| Surge current (10ms) | IFSM | 2 | Α |
| Power dissipation | Р | 150 | mW |
| Junction temperature | Tj | 125 | $^{\circ}\mathbb{C}$ |
| Storage temperature | Tstg | -55 to +125 | $^{\circ}\!\mathbb{C}$ |

■ Electrical Characteristics Ta = 25 °C

| Parameter | Symbol | Test Conditions | Min | Тур | Max | Unit |
|---------------------------------|-----------------|-------------------|-----|------|-----|------|
| Reverse breakdown voltage | VR | IR= 100 uA | 80 | | | |
| Forward voltage | VF1 | IF= 1 mA | | 0.61 | | V |
| | VF2 | IF= 10mA | | 0.74 | | V |
| | VF3 | IF= 100 mA | | 0.92 | 1.2 | |
| Reverse voltage leakage current | l _{R1} | VR=30 V | | | 0.1 | uA |
| | IR2 | VR=80 V | | | 0.5 | |
| Capacitance between terminals | Ст | VR= 0 V, f= 1 MHz | | 2.2 | 4 | pF |
| Reverse recovery time | trr | IF=10mA | | 1.6 | 4 | ns |

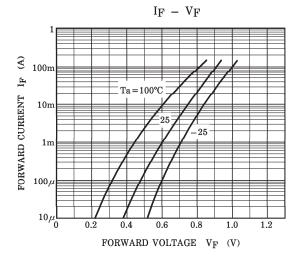
Marking

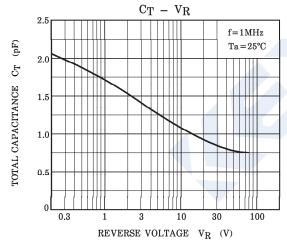
| Marking | A3 |
|---------|----|
| | , |

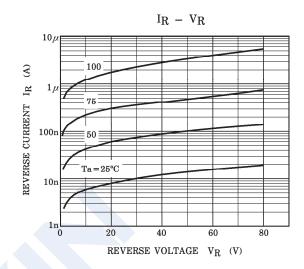
SMD Type Diodes

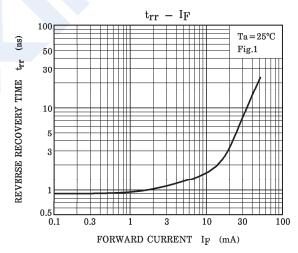
1SS181

■ Typical Characterisitics









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